

# **isc Silicon NPN Power Transistor**

## **DESCRIPTION**

- High Collector-Base Breakdown Voltage-
  - : V<sub>(BR)CBO</sub>= 1300V (Min.)
- · High Switching Speed
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

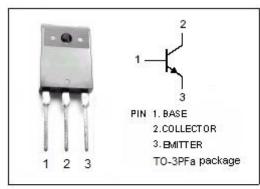
### **APPLICATIONS**

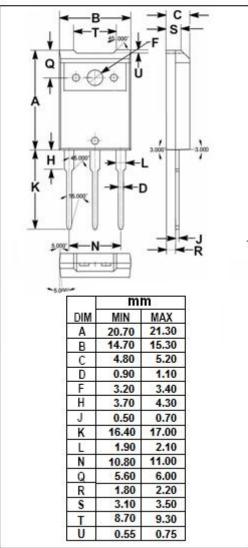
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• Designed for power switching applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	1300	V	
V <sub>CES</sub>	Collector- Emitter Voltage	1300	V	
V <sub>CEO</sub>	Collector-Emitter Voltage 700		V	
V <sub>EBO</sub>	Emitter-Base Voltage	7.7	V	
Ic	Collector Current-Continuous	5	А	
I <sub>B</sub>	Base Current-Continuous	3	А	
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃	80	W	
TJ	Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$ C	







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2SD1663

#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 0.5A; L= 50mH	700			V			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4.5A; I <sub>B</sub> = 2A			2.0	V			
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4.5A; I <sub>B</sub> = 2A			1.5	V			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7.7V; I <sub>C</sub> = 0			100	μА			
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 750V; I <sub>E</sub> = 0 V <sub>CB</sub> = 1300V; I <sub>E</sub> = 0			50 1.0	μA mA			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	18		50				
Switching times									
ton	Turn-On Time				1.0	μ <b>S</b>			
t <sub>stg</sub>	Storage Time	I <sub>C</sub> = 2.5A, I <sub>B1</sub> = 0.5A, I <sub>B2</sub> = -1A			3.0	μ <b>S</b>			
t <sub>f</sub>	Fall Time				0.5	μs			

#### **NOTICE:**

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